

# Fault Tolerant CAN - LDO

## **Final Data Sheet**

#### 1 Overview

#### 1.1 Features

- Standard fault tolerant differential CAN-transceiver (TLE6254 LS CAN cell)
- Bus failure management
- · Low power mode management
- CAN data transmission rate up to 125 kBaud
- Low-dropout voltage regulator 5V ± 2%
- Two Low Side Switches
- Three High Side Switches
- · Power on and under-voltage reset generator
- Vcc supervisor
- Window watchdog
- Programable time base
- Integrated fail-safe mechanism
- Standard 16 bit SPI-Interface
- · Wide input voltage and temperature range
- Enhanced power P-DSO-Package

Туре	Ordering Code	Package
TLE 6262 G	on request	P-DSO-28-6

#### Description

The TLE 6262 G is a monolithic integrated circuit in a P-DSO-28-6 package, which incorporates a failure tolerant low speed CAN-transceiver for differential mode data transmission, a low dropout voltage regulator for internal and external 5V supply as well as a 16 bit SPI interface to control and monitor the IC. Further there are integrated three high side switches, two low side switches, a window watchdog circuit and a reset circuit. Both, the window watchdog and reset function are referring to a time base that is programmable via an external resistor.

The IC is designed to withstand the severe conditions of automotive applications.

# TLE 6262 G





## **1.2 Pin Configuration**

(top view)







## 1.3 Pin Definitions and Functions

Pin No.	Symbol	Function
1	CANH	CAN-H bus line; HIGH in dominant state
2	RTH	Termination input for CANH
3	RO	Reset output; open drain output; integrated pull up; active low
4	CANL	CAN-L bus line; LOW in dominant state
5	RTL	Termination input for CANL
6, 7, 8, 9, 20, 21, 22, 23	GND	<b>Ground</b> ; to reduce thermal resistance place cooling areas on PCB close to this pins.
10	OUTH1	<b>High side output 1</b> ; controlled via PWM input and/or SPI input, short circuit protected
11	OUTL1	Low side output 1; SPI controlled, with active zener
12	OUTL2	Low side output 2; SPI controlled, with active zener
13	OUTH2	High side output 2; SPI controlled
14	OUTH3	<b>High side output 3</b> ; SPI controlled, in low power mode controlled by internal autotiming function if selected
15	Vs	<b>Power supply</b> ; block to GND directly at the IC with ceramic capacitor
16	CSN	<b>SPI interface chip select not</b> ; CSN is an active low input; serial communication is enabled by pulling the CSN terminal low; CSN input should only be transitioned when CLK is low; CSN has an internal active pull up and requires CMOS logic level inputs
17	DO	<b>SPI interface data out</b> ; this tristate output transfers diagnosis data to the control device; the output will remain 3-stated unless the device is selected by a low on Chip-Select-Not (CSN); see <b>table 3</b> for diagnosis protocol
18	DI	<b>SPI interface data in</b> ; receives serial data from the control device; serial data transmitted to DI is a 16 bit control word with the Least Significant Bit (LSB) being transferred first: the input has an active pull down and requires CMOS logic level inputs; DI will accept data on the falling edge of CLK-signal; see <b>table 2</b> for input data protocol
19	CLK	<b>SPI interface clock input</b> ; clocks the shiftregister; CLK has an internal active pull down and requires CMOS logic level inputs



## **1.3 Pin Definitions and Functions** (cont'd)

Pin No.	Symbol	Function
24	V <sub>CC</sub>	Output voltage regulator; 5V logic supply, block to GND with an 100nF external ceramic capacitor directly at the IC + external capacitor $C_Q \ge 22 \ \mu F$
25	RxD	CAN Receive data output;
26	TxD	CAN Transmit data input; integrated pull up
27	PWM	Pulse width control; for high side switch 1
28	OSC	<b>Oscillator input</b> ; time base for power on reset, watchdog window and stand by timer for HS3, to program connect external resistor to GND



## 1.4 Functional Block Diagram







## 1.5 Circuit Description

The TLE 6262 G is a monolithic IC, which incorporates a failure tolerant low speed CANtransceiver for differential mode data transmission, a low dropout voltage regulator for internal and external 5V supply as well as a SPI interface to control and monitor the IC. Further there are integrated three high side switches, two low side switches, a window watchdog circuit and a reset circuit. Both, the window watchdog and reset function are referring to a time base that is programmable via an external resistor.

Figure 2 shows a block schematic diagram of the TLE 6262 G

Feature	normal mode	Receive-only mode	v V <sub>BAT</sub> stand-by mode	
V <sub>CC</sub>	ON	ON	ON	
Reset	ON	ON	ON	
Watchdog	ON <sup>1)</sup>	ON <sup>1)</sup>	ON <sup>1)</sup>	
SPI	ON	ON	ON	
CAN transmit	ON	OFF	OFF	
CAN receive	ON	ON	OFF <sup>2)</sup>	
OUTHS 1 <sup>3) 4) 5)</sup>	ON	ON	ON	
OUTHS 2 <sup>3) 5)</sup>	ON	ON	ON	
OUTHS 3 <sup>3) 5)</sup>	ON	ON	ON	
OUTHS3-auto timing <sup>3) 5)</sup>	OFF	ON	ON	
OUTLS 1 <sup>3) 6)</sup>	ON	ON	ON	
OUTLS 2 <sup>3) 6)</sup>	ON	ON	ON	

#### Table 1: mode truth table

<sup>1)</sup> at low V<sub>CC</sub> output current only active when watchdog undercurrent function is not activated

<sup>2)</sup> a bus wake-up is monitored by setting the RxD output low

<sup>3)</sup> only active when selected via SPI

<sup>4)</sup> also active when driven via the PWM input

- <sup>5)</sup> automatically disabled when a reset occurs
- <sup>6)</sup> automatically disabled when a reset or watchdog reset respectively, occurs or the watchdog is disabled by the undercurrent function



#### **CAN Transceiver**

The TLE 6262 is optimized for low speed data transmission up to 125 kbaud in automotive applications. Normally a differential signal is transmitted or received respectively. When a bus wiring failure (see **table 4**) is detected the device automatically switches to a dedicated CANH or CANL single-wire mode to maintain the communication if necessary. Therefore it is equipped with one differential receiver and four single ended comparators (two for each bus line). To avoid false triggering by external RF influences the single wire modes are activated after a certain delay time. As soon as the bus failure disappears the transceiver switches back to differential mode after another time delay. The bus failures are monitored via the diagnosis protocol of the SPI. Therefore it is possible to distinguish 6 CAN bus failures or failure groups on the bits 8 to 13 (see **table 3**).

To reduce EMC caused by the transceiver the dynamic slopes of the CANL and CANH signals are both limited and symmetric. This allows the use of an unshielded twisted or parallel pair of wires for the bus. During single-wire transmission (bus-failure) the EMC performance of the system is degraded from the differential mode.

The differential receiver threshold is set to typ. -2.8 V. This ensures correct reception in the normal operation mode as well as in the failure cases 1, 2, 3a and 4 with a noise margin as high as possible. When one of the bus failures 3, 5, 6, 6a, and 7 is detected, the defective bus wire is disabled by switching off the affected bus termination and output stage.

The CAN-transceiver offers three different operation modes that are controlled via the SPI: the normal operation mode, Receive-only mode and  $V_{bat}$  stand-by mode. Please see the state diagram (**figure 3**). In the  $V_{bat}$  stand-by mode the RTL output voltage is switched to  $V_S$ .

In case of a wake-up via the bus lines or one of the bus lines respectively, the TLE 6262 automatically sets the RxD output LOW. To send respectively receive messages the CAN-transceiver can now be set in normal operation mode or receive-only mode by the microcontroller.

When a reset occurs the transceiver circuit is automatically switched to V<sub>bat</sub>-stand-by mode because the SPI input bits are automatically set LOW for this event.

A thermal shutdown of the CAN-transceiver circuit is monitored via the SPI diagnosis bit 15.







Figure 3: State Diagram

## Low Dropout Voltage Regulator

The TLE 6262 is able to drive external 5V loads up to 45 mA. Its output voltage tolerance is less than  $\pm$  2%. In addition the regulator circuit drives the internal loads like the CAN-transceiver circuit.

An external reverse current protection is recommended to prevent the output capacitor from being discharged by negative transients or low input voltage.

Stability of the output voltage is guaranteed for output capacitors  $C_{VCC} \ge 100$  nF. Nevertheless a lot of applications require a much larger output capacitance to buffer the output voltage in case of low input voltage or negative transients. Furthermore the due function of e.g. the reset and 3V-supervisor circuit are supported by a larger output capacitance because of their reaction times. Therefore a output capacitance  $C_{VCC} \ge 10 \ \mu\text{F}$  is recommended.



## SPI (serial peripheral interface)

The 16-bit wide programming word or input word (see table 1) is read in via the data input DI, and this is synchronized with the clock input CLK supplied by the  $\mu$ C. The diagnosis word appears synchronously at the data output DO (see **table 3**).

The transmission cycle begins when the chip is selected by the chip select not input CSN (H to L). After the CSN input returns from L to H, the word that has been read in becomes the new control word. The DO output switches to tristate status at this point.

For details of the SPI timing please refer to figure 3 to 7.

#### Oscillator

All internal delay times are referring to the internal oscillator frequency, which is set by an external resistor from pin OSC to GND. The oscillator frequency and the resulting internal cycling time can be calculated by the equations:

$$f_{OSC} = \frac{28,45 \times 10^9 [Hz\Omega]}{R_{OSC}}$$

$$t_{\rm CYL} = \frac{32}{f_{\rm OSC}}$$

#### Window Watchdog, Reset and 3V-Supervisor

When the output voltage V<sub>CC</sub> exceeds the reset threshold voltage V<sub>RT</sub> the reset output RO is switched HIGH after a delay time of 16 cycles. This is necessary for a defined start of the microcontroller when the application is switched on. As soon as an under-voltage condition of the output voltage (V<sub>CC</sub> < V<sub>RT</sub>) appears, the reset output RO is switched LOW again. The LOW signal is guaranteed down to an output voltage V<sub>CC</sub>  $\geq$  1V. Please refer to **fig.11**, reset timing diagram.

Should the output voltage fall short of the 3V-supervisor threshold V<sub>ST</sub> an internal flipflop is set LOW. The SPI diagnosis bit 7 monitors this. In normal operation this flip-flop has to be activated via the SPI input bit 7. This feature is useful e.g. to monitor that the RAM data of the microcontroller might be damaged or the application is connected to V<sub>S</sub> the first time.

After the above described delayed reset (LOW to HIGH transition of RO) the window watchdog circuit is started by opening a long open window of 32 cycles. Now the microcontroller has to service a watchdog trigger signal via the SPI interface (input bit 0). A watchdog trigger is detected as a falling edge by sampling for 2 cycles a HIGH followed by 2 cycles LOW of the SPI input bit 0. The long open window ensures a simple and fast



synchronization of the TLE 6262 watchdog timing to the watchdog services of the microcontroller.

After the first trigger the watchdog has to be serviced by meeting an open window of 20 cycles that follows a closed window of 12 cycles. A correct watchdog service immediately results in starting the next closed window. Please refer to **fig. 10**, watchdog timing diagram.

If the trigger signal does not meet the open window (trigger to early or to late) the reset output RO is set LOW for a period of 4 cycles. Afterwards a long open window is started again. In addition, the SPI diagnosis bit 2 is set HIGH to monitor a watchdog reset.

Both, the undervoltage reset and the watchdog reset are setting all SPI input bits LOW.

To avoid a cyclic wake-up of the microcontroller in low power mode (sleep mode) the watchdog circuit can be automatically disabled at low output currents ( $I_{CC} < I_{CCWD}$ ). To activate this feature the SPI input bit 8 has to be set HIGH. In this under-current mode the low side switches are switched off automatically by the TLE 6262 to guarantee fail-save operation of the application. When the microcontroller returns back to normal mode ( $I_{CC} > I_{CCWD}$ ) the first closed window is transformed to an open window so that the total open window time is 32 cycles. This ensures a more simple and fast synchronization of the TLE 6262 watchdog timing to the watchdog services of the microcontroller.

#### Flash program mode

To disable the watchdog feature a flash program mode is available. This mode is selected by applying a voltage of  $6.8V < V_{PWM} < 7.2V$  at pin PWM. This is useful e.g. if the flash-memory of the micro has to be programmed and therefore a regular watchdog triggering is not possible. If the SPI is required in the flash program mode to change e.g. the mode of the TLE6262 the first input telegram has to be "00000000".

## High Side Switch 1

The high side output OUTH1 is able to switch loads up to 250 mA. Its on-resistance is 1.0  $\Omega$  typ. @ 25°C. This switch can be controlled either via the PWM input or the SPI input bit 1. When the input PWM is used it has to be enabled by setting the SPI input bit 11 HIGH. In case of both control inputs being active the PWM signal is masked by the SPI signal (see **fig. 8**, High Side Switch 1 Timing Diagram).

The SPI diagnosis bit 14 monitors a thermal shutdown of the switches, whereas bit 0 flags a thermal prewarning. By this the microcontroller is able to reduce the power dissipation of the TLE 6262 by switching off functions of minor priority before the temperature threshold of the thermal shutdown is reached. Further OUTH1 is protected against short circuit and overload. The SPI diagnosis bit 1 indicates an overload of OUTH1. As soon as the under-voltage condition of the supply voltage is met (V<sub>S</sub> < V<sub>UVOFF</sub>), the switches are automatically disabled by the under-voltage lockout circuit.



This is flagged by the SPI diagnosis bit 3. Moreover the switches are disabled when a reset occurs.

## High Side Switch 2

The high side output OUTH2 is able to switch loads up to 250 mA. Its on-resistance is 1.0  $\Omega$  typ. @ 25°C. This switch is controlled via the SPI input bit 2.

The SPI diagnosis bit 14 monitors a thermal shutdown of the switches, whereas bit 0 flags a thermal prewarning. By this the microcontroller is able to reduce the power dissipation of the TLE 6262 by switching off functions of minor priority before the temperature threshold of the thermal shutdown is reached. As soon as the under-voltage condition of the supply voltage is met ( $V_S < V_{UVOFF}$ ), the switches are automatically disabled by the under-voltage lockout circuit. This is flagged by the SPI diagnosis bit 3. Moreover the switches are disabled when a reset occurs.

#### High Side Switch 3

The high side output OUTH3 is able to switch loads up to 150 mA. Its on-resistance is  $1.5 \Omega$  typ. @ 25°C. This switch is controlled via the SPI input bits 3 and 4. To supply external wake-up circuits in low power mode (sleep mode or Vbat-stand-by mode), the output OUTH3 can be periodically activated by the internal oscillator circuit. For activating this feature the SPI input bits 3 and 4 have to be set HIGH. The autotiming period is 128 internal cycle times; the on-time is 2 cycles. In case of a watchdog reset the autotiming period may be shorter.

The SPI diagnosis bit 14 monitors a thermal shutdown of the switches, whereas bit 0 flags a thermal prewarning. By this the microcontroller is able to reduce the power dissipation of the TLE 6262 by switching off functions of minor priority before the temperature threshold of the thermal shutdown is reached. As soon as the under-voltage condition of the supply voltage is met ( $V_S < V_{UVOFF}$ ), the switches are automatically disabled by the under-voltage lockout circuit. This is flagged by the SPI diagnosis bit 3. Moreover the switches are disabled when a reset occurs.

#### Low Side Switches 1/2

The two low side outputs OUTL1 and OUTL2 are able to switch loads up to 100 mA. Their on-resistance is  $1.5 \Omega$  (typ.) @ 25°C. This switches are controlled via the SPI input bits 5 and 6. In case of high inrush currents a built in zener circuit (typ. 37 V) activates the switches to protect them.

The SPI diagnosis bit 14 monitors a thermal shutdown of the switches, whereas bit 0 flags a thermal prewarning. By this the microcontroller is able to reduce the power dissipation of the TLE 6262 by switching off functions of minor priority before the temperature threshold of the thermal shutdown is reached. The SPI diagnosis bits 5/6



are giving a feedback about current status of OUTL1/OUTL2. As soon as the undervoltage condition of the supply voltage is met ( $V_S < V_{UVOFF}$ ), the switches are automatically disabled by the under-voltage lockout circuit. This is flagged by the SPI diagnosis bit 3. In addition the outputs OUTL1 and OUTL2 are also disabled when the watchdog is switched off in undercurrent state or when a reset occurs.



#### Table 2

## Input Data Protocol

BIT	
15	not used
14	not used
13	not used
12	not used
11	PWM Enable
10	CAN Enable Transmit
9	CAN Not Stand-By
8	Watchdog Control
7	Supervisor Enable
6	LS-Switch 2
5	LS-Switch 1
4	HS3 Auto Timing
3	HS-Switch 3
2	HS-Switch 2
1	HS-Switch 1
0	Watchdog Trigger
H = ON	·

L = OFF

#### Table 3

## **Diagnosis Data Protocol**

BIT	
15	Thermal Shutdown Transceiver
14	Thermal Shutdown Switches
13	CAN Failure 2 and 4
12	CAN Failure 1 and 3a
11	CAN Failure 6
10	CAN Failure 6a
9	CAN Failure 6a, 5 and 7
8	CAN Failure 3
7	Vcc < 3V
6	Status LS2
5	Status LS1
4	not used
3	Vs Undervoltage Lockout
2	Window Watchdog Reset
1	Overload HS1
0	Temperature Prewarning
H = ON	

L = OFF



## Table 4

# CAN bus line failure cases (according to ISO 11519-2)

failure #	failure description
1	CANL line interrupted
2	CANH line interrupted
3	CANL shorted to Vbat, CANL > 7.2 V
3a (no ISO failure)	CANL shorted to Vcc; 3.2 V < CANL < 7.2 V
4	CANH shorted to GND
5	CANL shorted to GND
6	CANH shorted to Vbat; CANH > 7.2 V
6a (no ISO failure)	CANH shorted to Vcc; 1.8 V < CANH < 7.2 V
7	CANL shorted to CANH



## 2 Electrical Characteristics

# 2.1 Absolute Maximum Ratings

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		

#### Voltages

Vs	-0.3	28	V	-
Vs	-0.3	40	V	$t_p$ < 0.5s; $t_p/T$ < 0.1
V <sub>CC</sub>	-0.3	5.5	V	
$V_{\mathrm{CANH/L}}$	-10	28	V	
$V_{CANH/L}$	-40	40	V	$V_{\rm S} > 0 V$ $t_p < 0.5 {\rm s}; t_p / T < 0.1$
V <sub>1</sub>	-0.3	V <sub>cc</sub> +0.3	V	$0 V < V_{S} < 24 V$ $0 V < V_{CC} < 5.5 V$
V <sub>DO/RO/RD</sub>	-0.3	V <sub>cc</sub> +0.3	V	$0 V < V_{S} < 24 V$ $0 V < V_{CC} < 5.5 V$
V <sub>TL /TH</sub>	-0.3	V <sub>s</sub> +0.3	V	$0 V < V_{S} < 24 V$ $0 V < V_{CC} < 5.5 V$
V <sub>ESD</sub>	-4000	4000	V	human body model; C = 100pF, R = 1.5kΩ
V <sub>ESD</sub>	-2000	2000	V	human body model; C = 100pF, R = $1.5k\Omega$
	$V_{\rm S}$ $V_{\rm CC}$ $V_{\rm CANH/L}$ $V_{\rm CANH/L}$ $V_{\rm I}$ $V_{\rm DO/RO/RD}$ $V_{\rm TL/TH}$ $V_{\rm ESD}$	$V_{\rm S}$ -0.3 $V_{\rm CC}$ -0.3 $V_{\rm CANH/L}$ -10 $V_{\rm CANH/L}$ -40 $V_{\rm I}$ -0.3 $V_{\rm DO/RO/RD}$ -0.3 $V_{\rm TL/TH}$ -0.3 $V_{\rm ESD}$ -4000	$V_{\rm S}$ -0.3       40 $V_{\rm CC}$ -0.3       5.5 $V_{\rm CANH/L}$ -10       28 $V_{\rm CANH/L}$ -40       40 $V_{\rm I}$ -0.3 $V_{\rm CC}$ $V_{\rm I}$ -0.3 $V_{\rm CC}$ $V_{\rm DO/RO/RD}$ -0.3 $V_{\rm CC}$ $V_{\rm DO/RO/RD}$ -0.3 $V_{\rm S}$ $V_{\rm TL/TH}$ -0.3 $V_{\rm S}$ $V_{\rm ESD}$ -4000       4000	$V_{\rm S}$ -0.3       40       V $V_{\rm CC}$ -0.3       5.5       V $V_{\rm CANH/L}$ -10       28       V $V_{\rm CANH/L}$ -40       40       V $V_{\rm CANH/L}$ -0.3 $V_{\rm CC}$ V $V_{\rm I}$ -0.3 $V_{\rm CC}$ V $V_{\rm DO/RO/RD}$ -0.3 $V_{\rm CC}$ V $V_{\rm DO/RO/RD}$ -0.3 $V_{\rm S}$ V $V_{\rm TL /TH}$ -0.3 $V_{\rm S}$ V $V_{\rm ESD}$ -4000       4000       V

#### Currents

Output current; Vcc	I <sub>CC</sub>	_	-	А	internally limited
Output current; OUTH1	I <sub>OUTH1</sub>	*)	0.3	А	*) internally limited
Output current; OUTH2	I <sub>OUTH2</sub>	-0.7	0.3	А	$t_p < 0.5$ s; $t_p/T < 0.1$
Output current; OUTH3	I <sub>outh3</sub>	-0.5	0.2	А	<i>t<sub>p</sub></i> < 0.5s; <i>t<sub>p</sub></i> / <i>T</i> < 0.1
Output current; OUTL1	I <sub>OUTL1</sub>	-0.2	0.4	А	$t_p < 0.5$ s; $t_p/T < 0.1$
Output current; OUTL2	I <sub>OUTL2</sub>	-0.2	0.4	А	$t_p < 0.5$ s; $t_p/T < 0.1$



## 2.1 Absolute Maximum Ratings (cont'd)

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		
Temperatures					
Junction temperature	Tj	-40	150	°C	_
Storage temperature	$T_{\rm stg}$	-50	150	°C	-

Note: Maximum ratings are absolute ratings; exceeding any one of these values may cause irreversible damage to the integrated circuit.



## 2.2 Operating Range

Parameter	Symbol	Limit Values		Unit	Remarks	
		min.	max.			
Supply voltage	Vs	$V_{\rm UVOFF}$	27	V	After $V_{\rm S}$ rising above $V_{\rm UV \ ON}$	
Supply voltage slew rate	$dV_{\rm S}/dt$	-0.5	5	V/μs	-	
Supply voltage increasing	Vs	-0.3	$V_{\rm UV  ON}$	V	Outputs in tristate	
Supply voltage decreasing	Vs	-0.3	$V_{\rm UVOFF}$	V	Outputs in tristate	
Logic input voltage (DI, CLK, CSN, PWM, TxD)	VI	-0.3	V <sub>cc</sub>	V	-	
Output current	I <sub>CC</sub>		35	mA		
Output current	I <sub>CC</sub>		45	mA	T < 0.1s	
Output capacitor	C <sub>cc</sub>	22		μF		
SPI clock frequency	$f_{\rm CLK}$	-	1	MHz	-	
OSC-Adjust Resistor	R <sub>osc</sub>	51	680	kΩ	<i>Ta</i> =-40°C; f = 10kHz	
Junction temperature	$T_i$	-40	150	°C	-	

#### **Thermal Resistances**

Junction pin	$R_{ m thj-pin}$	_	25	K/W	measured to pin 7
Junction ambient	$R_{ m thj-a}$	Ι	65	K/W	_

## Thermal Prewarning and Shutdown (junction temperatures)

Thermal prewarning ON temperature	$T_{\rm jPW}$	120	170	°C	bit 0 of SPI diagnosis word; hysteresis 30°K (typ.)
Thermal shutdown temp.	$T_{\rm jSD}$	150	200	°C	hysteresis 30°K (typ.)
Ratio of SD to PW temp.	$T_{\rm jSD}$ / $T_{\rm jPW}$	1.05	_	_	-
Thermal shutdown temp. CAN	$T_{\rm jSD}$	135	160	°C	hysteresis 10°K (typ.)



#### 2.3 Electrical Characteristics

 $9 V < V_S < 16 V$ ;  $I_{CC} = -100 \mu$ A; normal mode; all outputs open;  $-40 \circ C < T_j < 150 \circ C$ ; CAN-transceiver circuitry:  $-40 \circ C < T_j < 125 \circ C$ ; all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified.

Parameter	Symbol	Lir	Limit Values		Unit	Test Condition
		min.	typ.	max.		

#### Quiescent current Pin $V_{s}$

Current consumption	Is	_	5	10	mA	
Quiescent current $I_{SSB1} = I_S - I_{CC}$	$I_{\rm SSB1}$	_	180	280	μA	low power mode; V <sub>S</sub> =12V; T <sub>j</sub> =25°C

#### Voltage Regulator; Pin $V_{cc}$

Output voltage	V <sub>cc</sub>	4.9	5.0	5.2	V	0.1mA < I <sub>CC</sub> < 30mA
Output voltage	V <sub>cc</sub>	4.8	5.0	5.5	V	0A < <i>I</i> <sub>CC</sub> < 100μA
Line regulation	$\Delta V_{ m CC}$	-20		20	mV	9 V < $V_{\rm S}$ < 15 V; $I_{\rm CC}$ = 10mA
Load regulation	$\Delta V_{ m CC}$	-25		25	mV	0.1mA < I <sub>CC</sub> < 30mA; V <sub>S</sub> = 9V
Power supply ripple rejection	PSRR		40		dB	$V_{S} < 1 Vss;$ $C_{Q} \ge 22\mu F;$ 100Hz < f < 100kHz
Output current limit	$I_{\rm CCmax}$	45	60		mA	1)
Drop voltage $V_{\rm DR} = V_{\rm S}$ - $V_{\rm CC}$	V <sub>DR</sub>		0.15	0.45	V	I <sub>CC</sub> = 30 mA; see note 1)

#### **Oscillator; Pin OSC**

Oscillating frequency	$f_{\sf osc}$		62.8		kHz	$R_{OSC}$ = 453k $\Omega$
Internal cycling time $(1/32 * f_{OSC})^{-1}$	t <sub>CYL</sub>	383	509	637	μs	R <sub>OSC</sub> = 453kΩ

1) measured when the output voltage  $V_{\rm CC}$  has dropped 100 mV from the nominal value obtained at 13.5 V input voltage  $V_{\rm S}$ 



 $9 V < V_S < 16 V$ ;  $I_{CC} = -100 \mu$ A; normal mode; all outputs open;  $-40 \circ C < T_j < 150 \circ C$ ; CAN-transceiver circuitry:  $-40 \circ C < T_j < 125 \circ C$ ; all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified.

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		

#### Reset Generator; Pin RO

Reset threshold voltage	$V_{RT}$	4.0	4.3	4.65	V	
Reset low output voltage	V <sub>RO</sub>		0.2	0.4	V	$I_{RO} = 1mA$ $(V_{CC} \ge V_{RT}) \text{ or }$ $V_{CC} \ge 1V$ $(I_{RO} = 200 \ \mu\text{A})$
Reset high output voltage	V <sub>RO</sub>	4.0		V <sub>cc</sub> + 0.1	V	
Reset pull up current	I <sub>RO</sub>	20	150	500	μA	V <sub>RO</sub> = 0V
Reset reaction time	t <sub>RR</sub>	1	3	10	μs	$V_{CC} < V_{RT}$ to RO = L
Reset delay time (16 cyl.)	t <sub>RD</sub>	6.1	8.1	10.2	ms	$R_{OSC}$ = 453k $\Omega$

## 3 V Supervisor; (bit 7 of SPI diagnosis word)

Supervisor threshold voltage	$V_{\rm ST}$	2.3	2.7	3.1	V	
Supervisor reaction time	$t_{\rm SR}$	2	8	20	μs	$V_{CC} < V_{ST}$ to diagnosis bit 7 = L

#### Watchdog Generator

Watchdog trigger time	t <sub>WD</sub>	7.6	10	12.3	ms	$R_{OSC}$ = 453k $\Omega$
Closed window time (12 cyl.)	t <sub>CW</sub>	4.6	6.1	7.6	ms	$R_{OSC}$ = 453k $\Omega$
Open window time (20 cyl.)	t <sub>ow</sub>	7.7	10.2	12.7	ms	$R_{OSC}$ = 453k $\Omega$
Watchdog reset-puls time (4 cyl.)	t <sub>WDR</sub>	1.5	2.0	2.6	ms	$R_{OSC}$ = 453k $\Omega$
Watchdog activating current	I <sub>CCWD</sub>	2	4	12	mA	$T_{j}$ < 85 °C; Watchdog OFF when $I_{CC} < I_{CCWD}$ and SPI- input bit 8 = H
Watchdog activating current hysteresis	$I_{\rm CCWDhys}$		0.5		mA	



 $9 \text{ V} < V_{\text{S}} < 16 \text{ V}; I_{\text{CC}} = -100 \text{ }\mu\text{A};$  normal mode; all outputs open;  $-40 \text{ }^{\circ}\text{C} < T_{\text{j}} < 150 \text{ }^{\circ}\text{C};$  CAN-transceiver circuitry:  $-40 \text{ }^{\circ}\text{C} < T_{\text{j}} < 125 \text{ }^{\circ}\text{C};$  all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified.

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.	-	
Long open window (32 cyl.)	$I_{ m CCWDhys}$	12.2	16.2	20.4	ms	$R_{OSC}$ = 453k $\Omega$ sleep mode (WD OFF) to normal mode

#### Switches

#### Under-Voltage Lockout (bit 3 of SPI diagnosis word)

UV-Switch-ON voltage	$V_{\rm UV  ON}$	_	5.35	6.00	V	$V_{\sf S}$ increasing
UV-Switch-OFF voltage	$V_{\rm UVOFF}$	4.50	4.85	5.20	V	$V_{S}$ decreasing
UV-ON/OFF-Hysteresis	$V_{\rm UV  HY}$	-	0.5	-	V	$V_{\rm UV ON} - V_{\rm UV OFF}$

#### High Side Output OUTH1; (controlled by PWM or bit 1 of SPI input word)

Static Drain-Source	$R_{\rm DSONH1}$	_	1.0	2.0	Ω	
ON-Resistance; $I_{OUTH1}$ = -0.25 A			1.5	4.0	Ω	5.2 V $\leq V_{S} \leq$ 9 V
Active zener voltage	$V_{\rm OUTH1}$	-5.0	-3.0	-0.5	V	I <sub>OUTH1</sub> = – 0.25 Α
Clamp diode forward voltage	$V_{\rm OUTH1}$		0.8	1	V	I <sub>OUTH1</sub> = 0.25 Α
Leakage current	$I_{\rm OLH1}$	-100	-5	-	μA	$V_{\rm OUTH1}$ = 0 V
Switch ON delay time	t <sub>dONH1</sub>		10	100	μs	PWM to OUTH1; R <sub>L</sub> = 100 Ω
Switch OFF delay time	t <sub>dOFFH1</sub>		20	100	μs	PWM to OUTH1; R <sub>L</sub> = 100 Ω
Overcurrent shutdown threshold	$I_{\rm SDH1}$	-1.0	-0.6	-0.3	A	-
Shutdown delay time	t <sub>dSDH1</sub>	10	25	50	μs	
Current limit	I <sub>OCLH1</sub>	-2.0	-1.0	-0.5	А	



 $9 V < V_S < 16 V$ ;  $I_{CC} = -100 \mu$ A; normal mode; all outputs open;  $-40 \circ C < T_j < 150 \circ C$ ; CAN-transceiver circuitry:  $-40 \circ C < T_j < 125 \circ C$ ; all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified.

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		

#### PWM Input to control OUTH1; Pin PWM (high active)

H-input voltage threshold	V <sub>IH</sub>	_	_	$0.7 \times V_{CC}$	V	-
L-input voltage threshold	V <sub>IL</sub>	$0.2 \times V_{cc}$	_	_	V	-
Hysteresis of input voltage	V <sub>IHY</sub>	50	200	500	mV	-
Pull down current	$I_1$	5	25	180	μA	$V_{\rm I} = 0.2 * V_{\rm CC}$
Input capacitance	$C_{I}$	-	10	15	pF	0 V < V <sub>CC</sub> < 5.25 V

## High Side Output OUTH2; (controlled by bit 2 of SPI input word)

Static Drain-Source	$R_{\rm DSONH2}$	-	1.0	2.0	Ω	
ON-Resistance; $I_{OUTH2}$ = -0.25 A			1.5	4.0	Ω	5.2 V $\leq V_{\rm S} \leq$ 9 V
Active zener voltage	$V_{\rm OUTH2}$	-5.0	-3.0	-0.5	V	I <sub>OUTH2</sub> = – 0.25 Α
Clamp diode forward voltage	V <sub>OUTH2</sub>		0.8	1	V	I <sub>OUTH2</sub> = 0.25 Α
Leakage current	$I_{\rm OLH1}$	-100	-5	-	μA	$V_{OUTH2} = 0 V$
Switch ON delay time	t <sub>dONH1</sub>		10	100	μs	CSN high to OUTH2; R <sub>L</sub> = 100 $\Omega$
Switch OFF delay time	t <sub>dOFFH1</sub>		20	100	μs	CSN high to OUTH2; R <sub>L</sub> = 100 $\Omega$

## High Side Output OUTH3; (controlled by bit 3 and bit 4 of SPI input word)

Static Drain-Source	$R_{\rm DSONH3}$	_	1.5	3.0	Ω	
ON-Resistance; I <sub>OUTH3</sub> = -0.15 A			2.0	5.0	Ω	5.2 V $\leq V_{S} \leq$ 9 V
Active zener voltage	$V_{\rm OUTH3}$	-5.0	-3.0	-0.5	V	<i>I</i> <sub>OUTH3</sub> = – 0.15 A
Clamp diode forward voltage	$V_{\rm OUTH3}$		0.8	1	V	<i>I</i> <sub>OUTH3</sub> = 0.15 A
Leakage current	$I_{\rm OLH3}$	-100	-5	-	μA	V <sub>OUTH3</sub> = 0 V



 $9 \text{ V} < V_{\text{S}} < 16 \text{ V}; I_{\text{CC}} = -100 \text{ }\mu\text{A};$  normal mode; all outputs open;  $-40 \text{ }^{\circ}\text{C} < T_{\text{j}} < 150 \text{ }^{\circ}\text{C};$  CAN-transceiver circuitry:  $-40 \text{ }^{\circ}\text{C} < T_{\text{j}} < 125 \text{ }^{\circ}\text{C};$  all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified.

Parameter	Symbol	Limit Values		Unit	<b>Test Condition</b>	
		min.	typ.	max.		
Leakage current	I <sub>OLH3</sub>	_	5		μA	V <sub>OUTH3</sub> = 5 V
Switch ON delay time	t <sub>dONH3</sub>		10	100	μs	CSN high to OUTH3; R <sub>L</sub> = 100 $\Omega$
Switch OFF delay time	t <sub>dOFFH3</sub>		20	100	μs	CSN high to OUTH3; R <sub>L</sub> = 100 $\Omega$
Auto time period (128 cyl.)	t <sub>PH3</sub>	49	65	82	ms	$R_{OSC}$ = 453k $\Omega$ ; SPI-bit 4 = H, no WD reset
Auto time ON duty cycle (2 cyl.)	D.C.		1/64			referring to t <sub>PH3</sub>

## Low Side Output OUTL1 (bit 5 of SPI input word)

Static Drain-Source	$R_{\rm DSONL1}$	_	1.5	3.0	Ω	
ON-Resistance; $I_{OUTL1} = 0.1 \text{ A}$			2.0	5.0	Ω	5.2 V $\leq V_{S} \leq$ 9 V
Active zener clamp voltage	V <sub>OUTL1</sub>	32	37	42	V	<i>I</i> <sub>OUTL1</sub> = – 0.1 A
Leakage current	I <sub>OLL1</sub>			5	μA	V <sub>OUTL1</sub> =15 V; T <sub>j</sub> < 85°C
Switch ON delay time	t <sub>dONL1</sub>		5	50	μs	CSN high to OUTL1; R <sub>L</sub> = 100 $\Omega$
Switch OFF delay time	t <sub>dOFFL1</sub>		5	50	μs	CSN high to OUTL1; R <sub>L</sub> = 100 $\Omega$

## Low Side Output OUTL2 (bit 6 of SPI input word)

Static Drain-Source	$R_{\rm DSONL2}$	-	1.5	3.0	Ω	
ON-Resistance; $I_{OUTL2} = 0.1 \text{ A}$			2.0	5.0	Ω	5.2 V $\leq V_{\rm S} \leq$ 9 V
Active zener clamp voltage	$V_{\rm OUTL2}$	32	37	42	V	<i>I</i> <sub>OUTL2</sub> = – 0.1 A
Leakage current	$I_{\rm OLL2}$			5	μA	V <sub>OUTL2</sub> =15 V; T <sub>j</sub> < 85°C
Switch ON delay time	t <sub>dONL2</sub>		5	50	μs	CSN high to OUTL2; R <sub>L</sub> = 100 $\Omega$
Switch OFF delay time	$t_{\rm dOFFL2}$		5	50	μs	CSN high to OUTL2; R <sub>L</sub> = 100 $\Omega$



 $9 V < V_S < 16 V$ ;  $I_{CC} = -100 \mu$ A; normal mode; all outputs open;  $-40 \circ C < T_j < 150 \circ C$ ; CAN-transceiver circuitry:  $-40 \circ C < T_j < 125 \circ C$ ; all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified.

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		

#### **CAN-Transceiver**

#### **Receiver Output R×D**

HIGH level output voltage	V <sub>OH</sub>	V <sub>CC</sub> - 0.9	_	V <sub>CC</sub>	V	<i>I</i> <sub>0</sub> = – 250μA
LOW level output voltage	$V_{OL}$	0	_	0.9	V	I <sub>0</sub> = 1.25mA

#### Transmission Input T×D

HIGH level input voltage threshold	V <sub>IH</sub>		$0.52 \times V_{ m CC}$	$0.70  imes V_{ m CC}$	V	
LOW level input voltage threshold	V <sub>IL</sub>	$0.30  imes V_{ m CC}$	$0.48  imes V_{ m CC}$		V	
HIGH level input current	I <sub>IH</sub>	-140	-40	-10	μA	$V_i = 4 V$
LOW level input current	I <sub>IL</sub>	-600	-200	-40	μA	<i>V</i> <sub>i</sub> = 1 V

#### **Bus Lines CANL, CANH**

Differential receiver recessive-to-dominant threshold voltage	$V_{\mathrm{dRxD(rd)}}$	-2.8	-2.5	-2.2	V	
Differential receiver dominant-to-recessive threshold voltage	$V_{\mathrm{dRxD(dr)}}$	-3.1	-2.9	-2.5	V	
CANH recessive output voltage	$V_{CANHr}$	0.1	0.2	0.3	V	TxD = $V_{\rm CC}$ ; $R_{\rm RTH}$ < 4 k $\Omega$
CANL recessive output voltage	$V_{CANLr}$	V <sub>CC</sub> - 0.2	-	-	V	TxD = V <sub>CC</sub> ; R <sub>RTL</sub> < 4 kΩ
CANH dominant output voltage	$V_{CANHd}$	V <sub>CC</sub> -1.4	V <sub>CC</sub> -1.0	V <sub>CC</sub>	V	TxD = 0 V; I <sub>CANH</sub> = – 40 mA



 $9 \text{ V} < V_{\text{S}} < 16 \text{ V}; I_{\text{CC}} = -100 \text{ }\mu\text{A};$  normal mode; all outputs open;  $-40 \text{ }^{\circ}\text{C} < T_{\text{j}} < 150 \text{ }^{\circ}\text{C};$  CAN-transceiver circuitry:  $-40 \text{ }^{\circ}\text{C} < T_{\text{j}} < 125 \text{ }^{\circ}\text{C};$  all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified.

Parameter	Symbol	Li	mit Val	ues	Unit	<b>Test Condition</b>
		min.	typ.	max.		
CANL dominant output voltage	$V_{CANLd}$	-	1.0	1.4	V	TxD = 0 V; $I_{CANL} = 40 mA$
CANH output current	I <sub>CANH</sub>	-110	-80	-50	mA	V <sub>CANH</sub> = 0 V; TxD = 0 V
		-5	0	5	μA	sleep mode; V <sub>CANH</sub> = 12 V
CANL output current	$I_{CANL}$	50	80	110	mA	V <sub>CANL</sub> = 5 V; TxD = 0 V
		-5	0	5	μA	sleep mode; $V_{CANL} = 0 V;$ $V_{S} = 0 V$
Voltage detection threshold for short-circuit to battery voltage on CANH and CANL	V <sub>det(th)</sub>	6.5	7.3	8.0	V	normal operation mode
CANH wake-up voltage threshold	$V_{WAKEH}$	1.2	1.9	2.7	V	-
CANL wake-up voltage threshold	$V_{WAKEL}$	2.2	3.1	3.9	V	-
CANH single-ended receiver threshold	V <sub>CANH</sub>	1.6	2.1	2.6	V	failure cases 3, 5 and 7
CANL single-ended receiver threshold	$V_{CANL}$	2.4	3.0	3.4	V	failure case 6 and 6a
CANL leakage current	I <sub>CANLI</sub>	-5	0	5	μA	$V_{\rm CC} = 0 \text{ V}, V_{\rm S} = 0 \text{ V}, V_{\rm CANL} = 13.5 \text{ V}, T_{\rm j} < 85 ^{\circ}{\rm C}$
CANH leakage current	I <sub>canhi</sub>	-5	0	5	μA	$V_{CC} = 0 V; V_S = 0 V;$ $V_{CANH} = 5 V;$ $T_i < 85 °C$

## **Termination Outputs RTL, RTH**

RTL to <i>V<sub>CC</sub></i> switch-on resistance	R <sub>RTL</sub>	-	40	95	Ω	I <sub>o</sub> = – 10 mA;
RTL to BAT switch series resistance	R <sub>ortl</sub>	5	15	30	kΩ	V <sub>BAT</sub> -stand-by



 $9 \text{ V} < V_{\text{S}} < 16 \text{ V}; I_{\text{CC}} = -100 \text{ }\mu\text{A};$  normal mode; all outputs open;  $-40 \text{ }^{\circ}\text{C} < T_{\text{j}} < 150 \text{ }^{\circ}\text{C};$  CAN-transceiver circuitry:  $-40 \text{ }^{\circ}\text{C} < T_{\text{j}} < 125 \text{ }^{\circ}\text{C};$  all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified.

Parameter	Symbol	Li	mit Val	ues	Unit	<b>Test Condition</b>
		min.	typ.	max.		
RTH to ground switch-on resistance	R <sub>RTH</sub>	-	40	95	Ω	<i>I</i> <sub>o</sub> = 10 mA
RTH output voltage	V <sub>orth</sub>	-	0.7	1.0	V	I <sub>o</sub> = 1 mA; Vbat-stand-by mode
RTH pull-down current	$I_{RTHpd}$	40	75	120	μA	failure cases 6 and 6a
RTL pull-up current	I <sub>RTLpu</sub>	-120	-75	-40	μA	failure cases 3, 3a, 5 and 7



 $9 V < V_S < 16 V$ ;  $I_{CC} = -100 \mu$ A; normal mode; all outputs open;  $-40 \circ C < T_j < 150 \circ C$ ; CAN-transceiver circuitry:  $-40 \circ C < T_j < 125 \circ C$ ; all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified.

Parameter	Symbol	Lir	Limit Values		Unit	Test Condition
		min.	typ.	max.		

#### **CAN-Transceiver**

#### **Dynamic Characteristics**

CANH and CANL bus output transition time recessive-to- dominant	t <sub>rd</sub>	0.6	1.2	2.1	μs	10% to 90%; $C_1 = 10 \text{ nF};$ $C_2 = 0; R_1 = 100 \Omega$
CANH and CANL bus output transition time dominant-to- recessive	t <sub>dr</sub>	0.3	0.6	1.3	μs	10% to 90%; $C_1 = 1 \text{ nF}; C_2 = 0; R_1 = 100 \Omega$
Minimum dominant time for wake-up on CANL or CANH	t <sub>wu(min)</sub>	12	20	38	μs	stand-by mode; V <sub>S</sub> = 13.5 V
Failure cases 3 and 6 detection time	t <sub>fail</sub>	30	45	80	μs	
Failure case 6a detection time		2.0	4.8	8.0	ms	
Failure cases 5, 6, 6a and 7 recovery time		30	45	80	μs	
Failure cases 3 recovery time		250	500	750	μs	
Failure cases 5 and 7 detection time		1.0	2.0	4.0	ms	
Failure cases 5 detection time	t <sub>fail</sub>	0.4	1.0	2.4	ms	stand-by modes; V <sub>S</sub> = 13.5 V
Failure cases 6, 6a and 7 detection time		0.8	4.0	8.0	ms	stand-by modes; V <sub>S</sub> = 13.5 V
Failure cases 5, 6, 6a and 7 recovery time		0.4	1.0	2.4	μs	stand-by modes; V <sub>S</sub> = 13.5 V



 $9 V < V_S < 16 V$ ;  $I_{CC} = -100 \mu$ A; normal mode; all outputs open;  $-40 \circ C < T_j < 150 \circ C$ ; CAN-transceiver circuitry:  $-40 \circ C < T_j < 125 \circ C$ ; all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified.

Parameter	Symbol	Li	mit Val	ues	Unit	Test Condition
		min.	typ.	max.		
Propagation delay TxD-to-RxD LOW (recessive to dominant)	t <sub>PD(L)</sub>	_	1.5	2.1	μs	$C_1 = 100 \text{ pF};$ $C_2 = 0; R_1 = 100 \Omega; \text{ no}$ failures and bus failure cases 1, 2, 3a and 4
		_	1.7	2.4	μs	$C_1 = C_2 = 3.3 \text{ nF};$ $R_1 = 100 \Omega;$ no bus failure and failure cases 1, 2, 3a and 4
		_	1.8	2.5	μs	$C_1$ 100 pF; $C_2$ = 0; $R_1$ = 100 Ω; bus failure cases 3, 5, 6, 6a and 7
		_	2.0	2.6	μs	$C_1 = C_2 = 3.3 \text{ nF};$ $R_1 = 100 \Omega;$ bus failure cases 3, 5, 6, 6a and 7
Propagation delay TxD-to-RxD HIGH (dominant to recessive)	t <sub>PD(H)</sub>	_	1.5	2.0	μs	$C_1 = 100 \text{ pF};$ $C_2 = 0; R_1 = 100 \Omega; \text{ no}$ failures and bus failure cases 1, 2, 3a and 4
		_	2.5	3.5	μs	$C_1 = C_2 = 3.3 \text{ nF};$ $R_1 = 100 \Omega;$ no bus failure and failure cases 1, 2, 3a and 4
		-	1.0	2.1	μs	$C_1$ 100 pF; $C_2$ = 0; $R_1$ = 100 Ω; bus failure cases 3, 5, 6, 6a and 7
		_	1.5	2.6	μs	$C_1 = C_2 = 3.3 \text{ nF};$ $R_1 = 100 \Omega;$ bus failure cases 3, 5, 6, 6a and 7
Edge-count difference (falling edge) between CANH and CANL for failure cases 1, 2, 3a and 4 detection	n <sub>e</sub>	_	4	_	_	
Edge-count difference (rising edge) between CANH and CANL for failure cases 1, 2, 3a and 4 recovery		-	2	-	_	
TxD permanent dominant disable time	t <sub>TxD</sub>	1.3	2.0	3.5	ms	



 $9 V < V_S < 16 V$ ;  $I_{CC} = -100 \mu$ A; normal mode; all outputs open;  $-40 \circ C < T_j < 150 \circ C$ ; CAN-transceiver circuitry:  $-40 \circ C < T_j < 125 \circ C$ ; all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified.

Parameter	Symbol	Lir	Limit Values U		Unit	Test Condition
		min.	typ.	max.		

#### **SPI-Interface**

#### Logic Inputs DI, CLK and CSN

H-input voltage threshold	V <sub>IH</sub>	_	_	0.7 *	V	-
				V <sub>cc</sub>		
L-input voltage threshold	$V_{IL}$	0.3 *	-	-	V	-
		$V_{\rm CC}$				
Hysteresis of input voltage	$V_{\rm IHY}$	50	200	500	mV	-
Pull up current at pin CSN	$I_{\rm ICSN}$	-100	-25	-5	μA	$V_{\text{CSN}} = 0.7 \times V_{\text{CC}}$
Pull down current at pin DI and CLK	$I_{\rm ICLK/DI}$	5	25	100	μA	$V_{DI} = 0.2 \times V_{CC}$
Input capacitance at pin CSN, DI or CLK	$C_{I}$	-	10	15	pF	0 V < V <sub>CC</sub> < 5.25 V

#### Logic Output DO

H-output voltage level	V <sub>DOH</sub>	<i>V</i> <sub>cc</sub> – 1.0	<i>V</i> <sub>cc</sub> – 0.7	_	V	I <sub>DOH</sub> = 1 mA
L-output voltage level	$V_{\rm DOL}$	_	0.2	0.4	V	I <sub>DOL</sub> = – 1.6 mA
Tri-state leakage current	I <sub>dolk</sub>	-10	-	10	μA	$V_{\text{CSN}} = V_{\text{CC}}$ 0 V < $V_{\text{DO}}$ < $V_{\text{CC}}$
Tri-state input capacitance	C <sub>DO</sub>	—	10	15	pF	$V_{\rm CSN} = V_{\rm CC}$ 0 V < $V_{\rm CC}$ < 5.25 V

#### **Data Input Timing**

Clock period	t <sub>pCLK</sub>	1000	_	_	ns	-
Clock high time	t <sub>CLKH</sub>	500	-	-	ns	-
Clock low time	t <sub>CLKL</sub>	500	_	-	ns	-
Clock low before CSN low	$t_{\rm bef}$	500	_	_	ns	-



 $9 \text{ V} < V_{\text{S}} < 16 \text{ V}; I_{\text{CC}} = -100 \text{ }\mu\text{A};$  normal mode; all outputs open;  $-40 \text{ }^{\circ}\text{C} < T_{\text{j}} < 150 \text{ }^{\circ}\text{C};$  CAN-transceiver circuitry:  $-40 \text{ }^{\circ}\text{C} < T_{\text{j}} < 125 \text{ }^{\circ}\text{C};$  all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified.

Parameter	Symbol	Lir	nit Val	ues	Unit	<b>Test Condition</b>
		min.	typ.	max.		
CSN setup time	t <sub>lead</sub>	500	_	-	ns	-
CLK setup time	t <sub>lag</sub>	500	-	-	ns	-
Clock low after CSN high	t <sub>beh</sub>	500	_	-	ns	-
DI setup time	t <sub>DISU</sub>	250	_	-	ns	-
DI hold time	t <sub>DIHO</sub>	250	-	-	ns	-
Input signal rise time at pin DI, CLK and CSN	t <sub>rIN</sub>	-	-	200	ns	-
Input signal fall time at pin DI, CLK and CSN	t <sub>fIN</sub>	-	-	200	ns	-
Data Output Timing			1			•
DO rise time	t <sub>rDO</sub>	_	50	100	ns	C <sub>L</sub> = 100 pF
DO fall time	t <sub>fDO</sub>	_	50	100	ns	C <sub>L</sub> = 100 pF
DO enable time	t <sub>ENDO</sub>	_	_	250	ns	low impedance
DO disable time	t <sub>DISDO</sub>	_	-	250	ns	high impedance
DO valid time	t <sub>VADO</sub>	-	100	250	ns	$V_{\rm DO} < 0.2 V_{\rm CC};$ $V_{\rm DO} > 0.7 V_{\rm CC};$ $C_{\rm L} = 100 \ \rm pF$



#### 3 Timing Diagrams



Figure 4 Data Transfer Timing





#### Figure 5 SPI-Input Timing



#### Figure 6 Turn OFF/ON Time





Figure 7 DO Valid Data Delay Time and Valid Time







## Figure 9: High Side Switch1 Timing Diagram





## Figure 10: Watchdog Time-out Definitions



## Figure 11: Watchdog Timing Diagram











## 4 Application



Figure 13 Application Circuit



#### 5 Package Outlines



#### Sorts of Packing

Package outlines for tubes, trays etc. are contained in our Data Book "Package Information".

Dimensions in mm



Edition 1999-10-12

Published by Infineon Technologies AG St.-Martin-Strasse 53 D-81541 München © Infineon Technologies AG1999 All Rights Reserved.

#### Attention please!

The information herein is given to describe certain components and shall not be considered as warranted characteristics.

Terms of delivery and rights to technical change reserved.

We hereby disclaim any and all warranties, including but not limited to warranties of non-infringement, regarding circuits, descriptions and charts stated herein.

Infineon Technologies is an approved CECC manufacturer.

#### Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office in Germany or our Infineon Technologies Representatives worldwide (see address list).

#### Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.